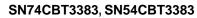


Sample &

Buy





SCDS003P - NOVEMBER 1992 - REVISED DECEMBER 2015

# SNx4CBT3383 10-Bit Bus-Exchange Switch

Technical

Documents

#### 1 Features

- High-Bandwidth Data Path (Up to 200 MHz)
- Low and Flat ON-State Resistance (r<sub>ON</sub>) Characteristics Over Operating Range  $(r_{ON} = 5 \Omega Typical)$
- Control Inputs Can Be Driven by TTL or 5-V and 3.3-V CMOS Outputs
- **Bidirectional Data Flow With Near-Zero** ٠ Propagation Delay
- Low Input and Output Capacitance Minimizes • Loading and Signal Distortion ( $C_{io(OFF)} = 6 \text{ pF}$ Typical)
- V<sub>CC</sub> Operating Range From 4.5 V to 5 V •
- Low Power Consumption ( $I_{CC} = 50 \mu A$  Maximum)

#### Applications 2

- **Enterprise Servers**
- **Ethernet Switches**
- Routers
- Servers
- Industrial PCs

# 3 Description

Tools &

Software

The SN74CBT3383 and SN54CBT3383 devices provide ten bits of high-speed TTL-compatible bus switching or exchanging. The low ON-state resistance of the switch allows connections to be made with minimal propagation delay.

Support &

Community

**.**...

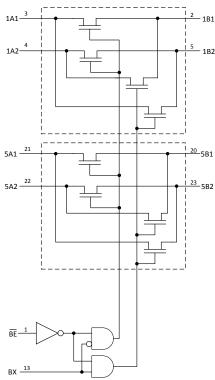
The devices operate as a 10-bit bus switch or a 5-bit bus exchanger, which provides swapping of the A and B pairs of signals. The bus-exchange function is selected when BX is high. The switches are connected when  $\overline{BE}$  is low.

## Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
SN74CBT3383DB	SSOP (24)	8.40 mm × 5.30 mm
SN74CBT3383DBQ	SSOP (24)	8.65 mm × 3.90 mm
SN74CBT3383DW	SOIC (24)	15.40 mm × 7.50 mm
SN74CBT3383PW	TSSOP (24)	7.80 mm × 4.40 mm
SNJ54CBT3383JT	CDIP (24)	32.00 mm × 6.92 mm
SN54CBT3383W	CFP (24)	14.35 × 9.08 mm

<sup>(1)</sup> For all available packages, see the orderable addendum at the end of the data sheet.

## Logic Diagram (Positive Logic)



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.



Features ..... 1

Applications ..... 1

Description ..... 1

Revision History..... 2

Pin Configuration and Functions ...... 3

Specifications...... 4

Absolute Maximum Ratings ...... 4

ESD Ratings ..... 4

Recommended Operating Conditions ...... 4

Thermal Information ...... 4

Switching Characteristics ...... 5

6.7 Typical Characteristics ...... 5

Detailed Description ......7

8.2 Functional Block Diagram ...... 7

2

# Table of Contents

8.3	Feature Description	8
8.4	Device Functional Modes	8
Арр	lication and Implementation	9
9.1	Application Information	9
9.2	Typical Application	9
Pow	ver Supply Recommendations	11
Lay	out	11
11.1	Layout Guidelines	11
11.2	Layout Example	11
Dev	ice and Documentation Support	12
12.1	Documentation Support	12
12.2	Related Links	12
12.3	Community Resources	12
12.4	Trademarks	12
12.5	Electrostatic Discharge Caution	12
12.6	Glossary	12
Mec	hanical, Packaging, and Orderable	
Info	rmation	12
	8.4 <b>App</b> 9.1 9.2 <b>Pow</b> <b>Lay</b> 11.1 11.2 <b>Dev</b> 12.1 12.2 12.3 12.4 12.5 12.6 <b>Mec</b>	<ul> <li>8.4 Device Functional Modes</li></ul>

## 4 Revision History

1

2

3

4

5

6

7

8

6.1

6.2

6.3

6.4

6.5

6.6

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

## Changes from Revision O (July 2004) to Revision P

Added Pin Configuration and Functions, Specifications, ESD Ratings, Detailed Description, Application and Implementation, Power Supply Recommendations, Layout, Device and Documentation Support, and Mechanical, Packaging, and Orderable Information......1

**ISTRUMENTS** 

EXAS

www.ti.com

Page



# 5 Pin Configuration and Functions

DB, DBQ, DW, JT, W, or PW Package 24-Pin SSOP, SOIC, CDIP, CFP, or TSSOP Top View						
BE	1 U	24	Vcc			
1B1 [	2	23	5B2			
1A1 [	3	22	5A2			
1A2 🛛	4	21	5A1			
1B2 🛛	5	20	5B1			
2B1 [	6	19	4B2			
2A1 [	7	18	4A2			
2A2 🛛	8	17	4A1			
2B2	9	16	4B1			
3B1 [	10	15	3B2			
3A1 [	11	14	] 3A2			
GND	12	13	]вх			

## **Pin Functions**

PIN		I/O	DESCRIPTION		
NO.	NAME	1/0	DESCRIPTION		
1	BE	I	Active-low input enable pin		
2	1B1	I/O	Transceiver I/O pin		
3	1A1	I/O	Transceiver I/O pin		
4	1A2	I/O	Transceiver I/O pin		
5	1B2	I/O	Transceiver I/O pin		
6	2B1	I/O	Transceiver I/O pin		
7	2A1	I/O	Transceiver I/O pin		
8	2A2	I/O	Transceiver I/O pin		
9	2B2	I/O	Transceiver I/O pin		
10	3B1	I/O	Transceiver I/O pin		
11	3A1	I/O	Transceiver I/O pin		
12	GND	—	Ground		
13	BX	I	Output select pin		
14	3A2	I/O	Transceiver I/O pin		
15	3B2	I/O	Transceiver I/O pin		
16	4B1	I/O	Transceiver I/O pin		
17	4A1	I/O	Transceiver I/O pin		
18	4A2	I/O	Transceiver I/O pin		
19	4B2	I/O	Transceiver I/O pin		
20	5B1	I/O	Transceiver I/O pin		
21	5A1	I/O	Transceiver I/O pin		
22	5A2	I/O	Transceiver I/O pin		
23	5B2	I/O	Transceiver I/O pin		
24	V <sub>CC</sub>	_	Power pin		

## 6 Specifications

## 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
$V_{CC}$	Supply voltage	-0.5	7	V
VI	Input voltage <sup>(2)</sup>	-0.5	7	V
I <sub>O</sub>	Continuos channel current		128	mA
I <sub>IK</sub>	Input clamp current (V <sub>I/O</sub> <0)		-50	mA
TJ	Junction temperature	-65	150	°C
T <sub>stg</sub>	Storage temperature	-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

## 6.2 ESD Ratings

			VALUE	UNIT
V	Electrostatic	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±3000	V
V <sub>(ESD)</sub>	discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±1000	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

## 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		4.5	5.5	V
VIH	High-level input voltage		2.0		V
VIL	Low-level input voltage			0.8	V
-	T <sub>A</sub> Operating free-air temperature	SN74CBT3383	0	70.0	°C
IA		SN54CBT3383	-55.0	125.0	

## 6.4 Thermal Information

		SN74CBT3383				
	THERMAL METRIC <sup>(1)</sup>	DB (SSOP)	DBQ (SSOP)	DW (SOIC)	PW (TSSOP)	UNIT
		24 PINS	24 PINS	24 PINS	24 PINS	
$R_{\thetaJA}$	Junction-to-ambient thermal resistance	63.0	61.0	46.0	88.0	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	33.5	22.1	19.9	26.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	32.0	-	19.33	-	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.



### 6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARA	PARAMETER TEST CONDITIONS		MIN	TYP <sup>(1)</sup>	MAX	UNIT			
VIK		$V_{CC} = 4.5 \text{ V}, \text{ I}_{\text{I}} =$	= –18 mA					-1.2	V
				SN54CBT3383	3			±5	
1		$v_{\rm CC} = 5.5 \ v, \ v_{\rm I}$	= 5.5 V or GND	SN74CBT3383	3			±1	μA
I <sub>CC</sub>		$V_{CC}$ = 5.5 V, I <sub>O</sub>	= 0, $V_I = V_{CC}$ or GNI	)				50	μA
$\Delta I_{CC}^{(2)}$	Control inputs	$V_{CC} = 5.5 V,$ One input at 3.4 Other inputs at	•				2.5	mA	
<u>_</u>	Control	$V_{I} = 3 V \text{ or } 0$		SN74CBT3383	3		3		pF
Ci	inputs	V <sub>I</sub> = 2.5 V		SN54CBT3383				5	
0		$V_0 = 3 V \text{ or } 0, \overline{R}$	BE = V <sub>CC</sub>	SN74CBT3383	3		6		pF
C <sub>io(OFF)</sub>		$V_0 = 2.5 \text{ V}, \overline{\text{BE}}$	= V <sub>CC</sub>	SN54CBT3383	3			6	
				L 64 m A	SN54CBT3383		5	9.2	
		$V_{CC} = 4.5 V$ $V_{I} = 2.4 V, I_{I} = 15 mA$	$V_1 = 0$	I <sub>I</sub> = 64 mA	SN74CBT3383		5	7	
r <sub>on</sub> <sup>(3)</sup>				I <sub>I</sub> = 30 mA	SN74CBT3383		5	7	Ω
			V <sub>1</sub> = 2.4 V, I <sub>1</sub> = 15 SN54CBT338	3		10	17		
			SN74CBT3383	3		10	15		

(1) Typical values are at  $V_{CC} = 5 V$ ,  $T_A = 25^{\circ}C$ .

(2) This is the increase in supply current for each input that is at the specified TTL voltage level, rather than  $V_{CC}$  or GND.

(3) Measured by the voltage drop between the A and B terminals at the indicated current through the switch. On-state resistance is determined by the lowest voltage of the two (A or B) terminals.

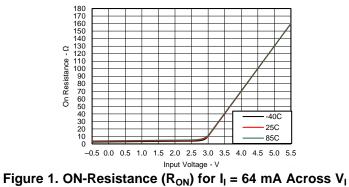
## 6.6 Switching Characteristics

over recommended ranges of supply voltage and operating free-air temperature range,  $C_L = 50 \text{ pF}$  (unless otherwise noted) (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	MAX	UNIT
+ (1)	A ar D	DanA	SN54CBT3383		1.5	
t <sub>pd</sub> <sup>(1)</sup>	A or B	B or A	SN74CBT3383		0.25	ns
•	DY	A or D	SN54CBT3383	1	10.2	~~~
t <sub>pd</sub>	BX	A or B	SN74CBT3383	1	9.2	ns
	BE	A an D	SN54CBT3383	1	10.8	
t <sub>en</sub>	BE	A or B	SN74CBT3383	1	8.6	ns
	BE	A or D	SN54CBT3383	1	8.2	20
t <sub>dis</sub>	BE	A or B	SN74CBT3383	1	7.5	ns

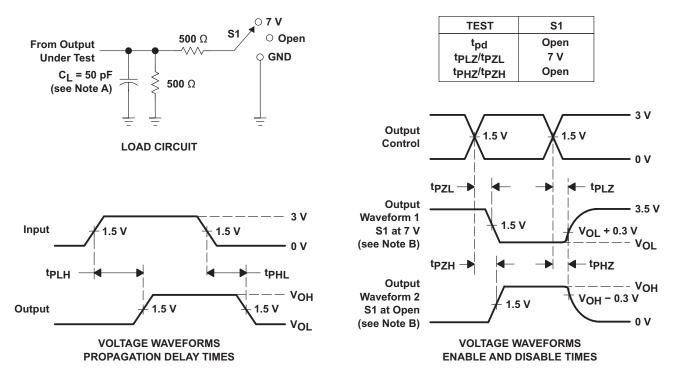
(1) The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

## 6.7 Typical Characteristics





## 7 Parameter Measurement Information



NOTES: A. C<sub>I</sub> includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.

- C. All input pulses are supplied by generators having the following characteristics: PRR $\leq$  10 MHz, Z<sub>Q</sub> = 50  $\Omega$ , t<sub>r</sub>  $\leq$  2.5 ns, t<sub>f</sub>  $\leq$  2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .

F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ . G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

## Figure 2. Load Circuit and Voltage Waveforms

6

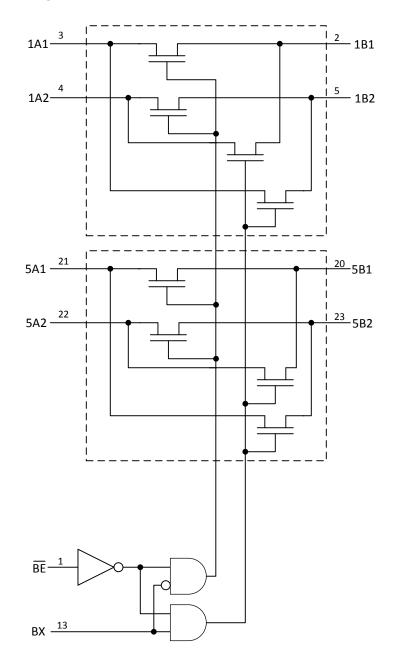


## 8 Detailed Description

## 8.1 Overview

The SNX4CBT3383 provides ten high-speed CMOS TTL-compatible bus switches. The low ON-resistance of the SNX4CBT3383 allows inputs to be connected to outputs without adding propagation delay and without generating additional ground bounce noise. The Bus Enable (BE) signal turns the switches on. The Bus Exchange (BX) signal provides nibble swap of the 1A and 1B pairs of signals. This exchange configuration allows byte swapping of buses in systems. It can also be used as a 5-wide, 2-to-1 multiplexer, to create low delay barrel shifters, and so forth.

## 8.2 Functional Block Diagram



TEXAS INSTRUMENTS

www.ti.com

## 8.3 Feature Description

## 8.3.1 Bidirectional Data Flow With Near-Zero Propagation Delay

The SN74CBT3383 features a low propagation delay or  $t_{pd}$  that works great for multiple rail information transfer from 1A1to 1B1 and 1A2 to 1B2 for example. However, the SNX4CBT3383 also features BUS exchange functionality, which allows for bidirectional data transfers from the inputs and outputs connected on the B side. By enabling the BX pin, the outputs are now crossed, or exchanged, and data can now flow from 1A1 to 1B2 and 1A2 to 1B1 with little to no propagation delay. This can be used to enable byte swapping of buses within a system or to create a 5-wide, 2-to-1 multiplexer.

## 8.4 Device Functional Modes

Table 1 lists the functional modes of the SNx4CBT3383.

INPUTS		INPUTS / OUTPUT		
BE	BX	1A1-5A1	1A2-5A2	
L	L	1B1-5B1	1B2-5B2	
L	Н	1B2-5B2	1B1-5B1	
Н	Х	Z	Z	

## Table 1. Function Table

8



## 9 Application and Implementation

## NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

## 9.1 Application Information

The SN74CBT3383 can be used to multiplex up to 5 channels simultaneously in a 2:1 configuration. The application shown here is a 2-bit bus being multiplexed between two devices. The BE and BX pins are used to control the chip from the bus controller. This is a very generic example, and could apply to many situations. If an application requires only one bit control or exchange, remember to tie the unused bit to high or low. By using another bus controller you can enable exchange across A1 and A2 to B1 and B2, allowing for greater system communication.

## 9.2 Typical Application

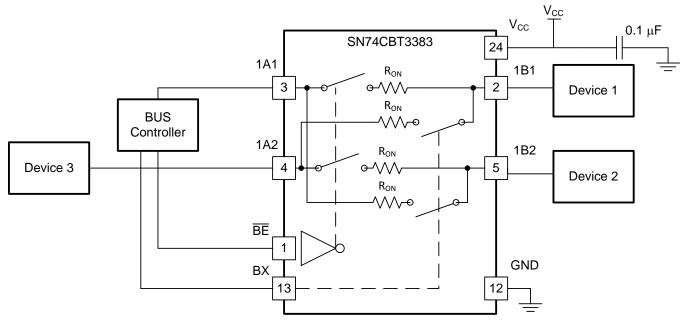


Figure 3. 1:2 Multiplexer or Bus and Selector Using 1 Bus Controller

## 9.2.1 Design Requirements

- 1. Recommended Input Conditions:
  - For specified high and low levels, see V<sub>IH</sub> and V<sub>IL</sub> in *Recommended Operating Conditions*.
- 2. Recommended Output Conditions:
  - Load currents must not exceed 128 mA per channel.
- 3. Frequency Selection Criterion:
  - Maximum frequency tested is 200 MHz.
  - Added trace resistance and capacitance can reduce maximum frequency capability; use layout practices as directed in *Layout*.

TEXAS INSTRUMENTS

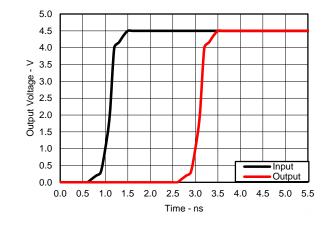
## **Typical Application (continued)**

### 9.2.2 Detailed Design Procedure

The 2-bit bus is connected directly to the 1A1, 1A2 on the SN74CBT3383, which essentially combines in the bus controller to form a single input or split bus bits. When BE is low and BX is low, the selected bus is using 1A1 and 1B1 as inputs and outputs. This means that Device 1 is connected to the bus controller and Device 2 is connected to Device 3 when BE is low and BX is low. While keeping BE low and using BX high, we can enable communication from the bus controller to Device 2 and from Device 1 to Device 3. This setup is especially useful when two controllers or devices need to share the same data from Device 1 and Device 2 and the bus addresses are limited or hard coded.

The 0.1-µF capacitor on V<sub>CC</sub> is a decoupling capacitor and should be placed as close as possible to the device.

## 9.2.3 Application Curve







## **10** Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating listed in the *Recommended Operating Conditions* table. Each V<sub>CC</sub> terminal must have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1- $\mu$ F bypass capacitor is recommended. If multiple pins are labeled V<sub>CC</sub>, then a 0.01- $\mu$ F or 0.022- $\mu$ F capacitor is recommended for each V<sub>CC</sub> because the V<sub>CC</sub> pins are tied together internally. For devices with dual-supply pins operating at different voltages, for example V<sub>CC</sub> and V<sub>DD</sub>, a 0.1- $\mu$ F bypass capacitor is recommended for each supply pin. To reject different frequencies of noise, use multiple bypass capacitors in parallel. Capacitors with values of 0.1  $\mu$ F and 1  $\mu$ F are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

## 11 Layout

## 11.1 Layout Guidelines

Reflections and matching are closely related to the loop antenna theory but are different enough to be discussed separately from the theory. When a PCB trace turns a corner at a 90° angle, a reflection can occur. A reflection occurs primarily because of the change of width of the trace. At the apex of the turn, the trace width increases to 1.414 times the width. This increase upsets the transmission-line characteristics, especially the distributed capacitance and self-inductance of the trace which results in the reflection. Not all PCB traces can be straight and therefore some traces must turn corners. Figure 5 shows progressively better techniques of rounding corners. Only the last example (BEST) maintains constant trace width and minimizes reflections.

## 11.2 Layout Example

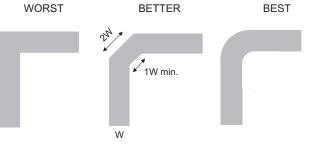


Figure 5. Trace Example

TEXAS INSTRUMENTS

www.ti.com

## **12 Device and Documentation Support**

## **12.1** Documentation Support

### 12.1.1 Related Documentation

For related documentation, see Voltage Clamps Made Easy, SCEA045.

## 12.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 2, Related Links

PARTS PRODUCT FOLDER		SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY			
SN74CBT3383	Click here	Click here	Click here	Click here	Click here			
SN54CBT3383	Click here	Click here	Click here	Click here	Click here			

## 12.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E<sup>™</sup> Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support TI's Design Support** Quickly find helpful E2E forums along with design support tools and contact information for technical support.

## 12.4 Trademarks

E2E is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

## 12.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## 12.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



## PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead finish/	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	Ball material	(3)		(4/5)	
							(6)				
SN74CBT3383DBQR	ACTIVE	SSOP	DBQ	24	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	0 to 70	CBT3383	Samples
SN74CBT3383DBR	LIFEBUY	SSOP	DB	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	CU383	
SN74CBT3383DW	LIFEBUY	SOIC	DW	24	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	CBT3383	
SN74CBT3383DWR	LIFEBUY	SOIC	DW	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	CBT3383	
SN74CBT3383PW	LIFEBUY	TSSOP	PW	24	60	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	CU383	
SN74CBT3383PWR	LIFEBUY	TSSOP	PW	24	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	CU383	

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and



continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



Texas

\*All dimensions are nominal

STRUMENTS

## TAPE AND REEL INFORMATION





### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74CBT3383DBQR	SSOP	DBQ	24	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74CBT3383DBR	SSOP	DB	24	2000	330.0	16.4	8.2	8.8	2.5	12.0	16.0	Q1
SN74CBT3383DWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
SN74CBT3383PWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1



# PACKAGE MATERIALS INFORMATION

3-Jun-2022



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74CBT3383DBQR	SSOP	DBQ	24	2500	356.0	356.0	35.0
SN74CBT3383DBR	SSOP	DB	24	2000	356.0	356.0	35.0
SN74CBT3383DWR	SOIC	DW	24	2000	350.0	350.0	43.0
SN74CBT3383PWR	TSSOP	PW	24	2000	356.0	356.0	35.0

## TEXAS INSTRUMENTS

www.ti.com

3-Jun-2022

# TUBE



# - B - Alignment groove width

\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
SN74CBT3383DW	DW	SOIC	24	25	506.98	12.7	4826	6.6
SN74CBT3383PW	PW	TSSOP	24	60	530	10.2	3600	3.5

DBQ (R-PDSO-G24)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.

D. Falls within JEDEC MO-137 variation AE.



# **PW0024A**



# **PACKAGE OUTLINE**

# TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



# PW0024A

# **EXAMPLE BOARD LAYOUT**

# TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# PW0024A

# **EXAMPLE STENCIL DESIGN**

# TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AD.



# **MECHANICAL DATA**

MSSO002E - JANUARY 1995 - REVISED DECEMBER 2001

# DB (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-150



## IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2023, Texas Instruments Incorporated